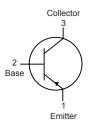
Bipolar Transistor



RoHS Compliant







Description:

A epitaxial silicon PNP planar transistor in a TO-39 type package designed for use as drivers for high power transistors in general purpose amplifier and switching circuits.

Maximum Ratings:

Characteristic	Symbol	Rating	Unit		
Collector - Base Voltage	V_{CBO}	80			
Collector - Emitter Voltage	V _{CEO}	60	V		
Emitter - Base Voltage		6			
Collector Current	T Ic	1	A		
Base Current	I _B	500	mA		
Total Device Dissipation (T _A = +25°C)	В	1	W		
Total Device Dissipation(T _C = +25°C)	P _{tot}	6	VV		
Operating Junction Temperature Range	T _J	+200	°C		
Storage Temperature Range	T _{stq}	-65 to +200			
Thermal Resistance, Junction-to-Case	R_{thJC}	29	°C/W		



Bipolar Transistor

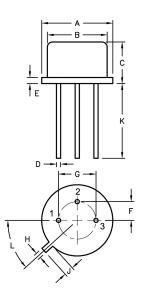


Electrical Characteristics: (T_A = +25°C Unless otherwise specified)

Parameter	Symbol	nbol Test Conditions		Max	Unit
	I _{CBO}	V _{CB} = 60V, I _E = 0	-	100	μA
Collector Cutoff Current	I _{CEV}	V _{CE} = 80V, V _{BE} = -1.5V			μA
		$V_{CE} = 50V, V_{BE} = -1.5V, T_{C} = +150^{\circ}C$		1	mA
Emitter Cutoff Voltage	I _{EBO}	$V_{EB} = 6V, I_{C} = 0$		500	μA
Collector - Emitter Sustaining Voltage	V _{CEO(sus)}	I _C = 100mA, I _B = 0, (Note1)	60	-	V
Collector Freitter Coturation Valtage	V _{CE(sat)}	I _C = 500mA, I _B = 50mA, (Note1)	-	0.3	
Collector - Emitter Saturation Voltage		$I_{\rm C}$ = 1A, $I_{\rm B}$ = 100mA, (Note1)		0.6	
Base - Emitter On Voltage	V _{BE(on)}	$V_{CE} = 1V, I_{C} = 250 \text{mA}$		1	
DC Current Gain	h _{FE}	L = 10 \/ = 1\/ (Note 1)	30	150	-
DC Current Gain		$I_{\rm C}$ = 1A, $V_{\rm CE}$ = 1V, (Note 1)	15	-	
Collector - Base Capactiance	C _{cbo}	V _{CB} = 10V, I _E = 0, f = 1MHz	-	100	pF
Small - Signal Current Gain	h _{fe}	$V_{CE} = 10V, I_{C} = 100mA, f = 1kHz$	30	-	-

Note:

1. Pulse Duration : ≤300µs, Duty Cycle ≤2%



Dimensions	Α	В	С	D	E	F	G	Н	I	J	K
Min.	8.5	7.74	6.09	0.4	-	2.41	4.82	0.71	0.73	12.7	42°
Max.	9.39	8.5	6.6	0.53	0.88	2.66	5.33	0.86	1.02	-	48°

Dimensions: Millimetres

Pin Configuration:

- 1. Emitter
- 2. Base
- 3. Collector

Part Number Table

Description	Part Number				
Transistor, PNP, 3A, 60V, TO-39	2N4238				

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